

Cellular

BTS / Repeater

Up Converter Mixer with AK1575 Fractional-N Frequency Synthesizer and VCO

1. Overview

AK1575 is the up-converter mixer with fractional-N frequency synthesizer and integrated VCO. AK1575 is targeted at the application that requires a high linearity performance in frequency conversion. The mixer block is comprised of the differential input and the differential output. Input frequency range is from 20MHz to 500MHz and output frequency range is from 690MHz to 4000MHz. The current consumption and the analog performance can be adjusted by a resistance connected to BIAS pin. The power supply voltage of mixer covers 4.75 to 5.25V.

The local signal output frequency range is from 262.5MHz to 4400MHz generated by internal VCO, synthesizer and divider. Not only a local signal is supplied to an internal mixer, but also can be taken to outside. A power supply voltage range of VCO/synthesizer is 2.7V to 3.6V or 4.75V to 5.25V. The CPU interface is 24bit serial data and its voltage is ranging from 2.7V to 5.25V

2. Features

General RF output frequency Range 690MHz to 4.0GHz IF input frequency Range 20MHz to 500MHz LO frequency Range 262.5MHz to 4.4GHz Supply Voltage: 4.75V to 5.25 V (Mixer) 2.7 to 3.6V / 4.75 to 5.25V (Synthesizer /VCO) Current Consumption: 150mA typ. Package: 32pin QFN (0.5mm pitch, 5mm \times 5mm \times 0.85mm) Operating Temperature : -40° C ~ 85° C Synthesizer/VCO Normalized Phase Noise -218dBc/Hz Phase Noise -111dBc/Hz @ 100kHz $f_0=2.1GHz$ Mixer $(f_{rf}=2GHz)$ Conversion Gain -1.5dB typ. Input 3rd orders intercept point +24dBm typ. Noise Figure 13dB typ. **Application** Microwave Radio Link

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4. Block Diagram and Function

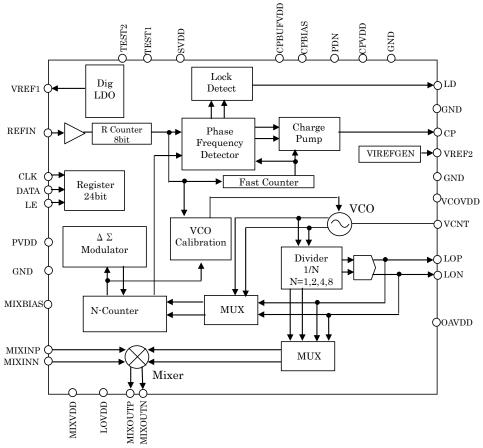


Fig. 1 Block diagram

Block function description

Block	Function
Mixer	Frequency Mixer which converts RF signal to IF signal
N divider	Frequency divider which divides the signal of VCO and pass it to phase frequency detector
$\Delta\Sigma$ Modulator	Control the modulus of N divider and realize fractional dividing
R counter	Frequency divider which divides the signal of reference clock and pass it to phase frequency detector
PFD (Phase Frequency Detector)	Detect a phase difference between the divided VCO signal and comparison frequency, and then drive the charge pump
Charge Pump	Output the electric charge according to the phase difference detected by PFD
VCO	The voltage controlled oscillator divided into three bands

5. Pin function Description and Assignment

1. Pin Functions

No	Name	I/O	Pin function	Power Down	Remarks
1	VREF1	AO	Connecting a capacitor to the ground plane		
2	PVDD	P	Synthesizer Power Supply		
3	GND	G			
4	MIXBIAS	AI	Connecting a resistor to the ground plane		
5	MIXINN	AI	Mixer Input		
6	MIXINP	AI	Mixer complementary Input		
7	MIXVDD	P	Mixer Power Supply		
8	LOVDD	P	Mixer Local Power Supply		
9	MIXOUTP	AO	Mixer Output		Open collector
10	MIXOUTN	AO	Mixer complementary Output		Open collector
11	PDN	DI	Power Control A logic low on this pin powers down the device		Schmidt trigger input
12	LE	DI	Load Enable		Schmidt trigger input
13	CLK	DI	Serial Clock Input		Schmidt trigger input
14	DATA	DI	Serial Data Input		Schmidt trigger input
15	LD	DO	Lock Detect Output	LOW	30 1
16	SVDD	P	Interface Power Supply		
17	LOP	AIO	Local complementary Input / Output		
18	LON	AIO	Local Input / Output		
19	OAVDD	P	Local Output Amplifier Power Supply		
20	GND	G			
21	VCNT	AI	Control Input to VCO		
22	VREF2	AO	Connecting a capacitor to the ground plane		
23	GND	G			
24	VCOVDD	P	VCO Power Supply		_
25	CPBIAS	AI	Connecting a resistor to the ground plane		
26	СР	AO	Charge Pump Output	Tri-St ate	
27	GND	G			
28	CPVDD	P	Charge Pump Power Supply		
29	CPBUFVDD	P	Charge Pump Pre-Buffer Power Supply		

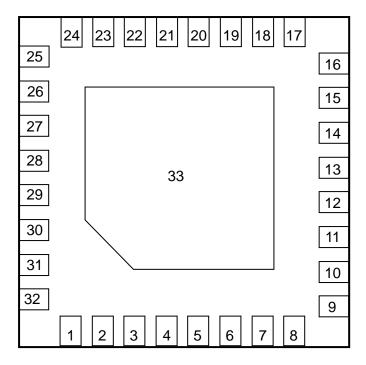
No	Name	I/O	Pin function	Power Down	Remarks
30	TEST1	DI	Test enable A logic low on this pin test mode the device.		Pull Down Schmidt trigger input
31	TEST2	DI	Test enable A logic low on this pin test mode the device.		Pull Down Schmidt trigger input
32	REFIN	ΑI	Reference Input		

Note 1) The exposed pad at the center of the backside should be connected to ground.

The following table shows the meaning of abbreviations used in the "I/O" column above.

AI:Analog input pin	AO:Analog output pin	AIO:Analog I/O pin	DI:Digital input pin
DO:Digital output pin	P: Power supply pin	G:Ground pin	

2. Pin Assignments



32pin QFN (0.5mm pitch, 5mm x 5mm)

Fig. 2 Package Pin Layout (Top View)

6. Absolute Maximum Rating

Parameter	Symbol	Min.	Max.	Unit	Remarks
	VDD1	-0.3	5.5	V	Note1, Note2
Supply Voltage	VDD2	-0.3	5.5	V	Note 3
	VDD3	-0.3	5.5	V	Note4
Ground Level	VSS	0	0	V	Note5
Maximum RF Input Level	RFPOW		12	dBm	Note6
Maximum Lo Input Level	LOPOW		12	dBm	Note7
Analog Input Voltage	VAIN	VSS-0.3	VDD3+0.3	V	Note1, Note8
Digital Input Voltage1	VDIN1	VSS-0.3	VDD1+0.3	V	Note1, Note9
Digital Input Voltage 2	VDIN2	VSS-0.3	VDD3+0.3	V	Note1, Note10
Input Current	IIN	-10	10	mA	
Storage Temperature	Tstg	-55	125	°C	

Note1 All voltage reference ground Level: 0V

Note2 Applied to the [SVDD] pin

Note3 Applied to the [MIXVDD] and [LOVDD] pins

Note4 Applied to the [CPVDD], [CPBUFVDD], [PVDD], [VCOVDD] and [OAVDD] pins

Note5 Applied to the All [GND] pins

Note6 Applied to the [MIXINP] and [MIXINN] pins

Note7 Applied to the [LOP] and [LON] pins

Note8 Applied to the [VCNT] and [REFIN] pins

Note9 Applied to the [CLK], [DATA], [LE] and [PDN] pins

Note10 Applied to the [TEST1] and [TEST2] pins

Exceeding these maximum ratings may result in damage to the AK1575. Normal operation is not guaranteed at these extremes.

7. Recommended Operating Range

Parameter	Symbol	Min.	Тур.	Max.	Unit	Remarks
Operating Temperature	Та	-40		85	°C	
-	VDD1	2.7	3.0	5.25	V	
	VDD2	4.75	5	5.25	V	
Supply Voltage	VDD2	2.7	3	3.6	V	
	VDD3	4.75	5	5.25	V	

Note1 Applied to the [SVDD] pin

Note2 Applied to the [MIXVDD] and [LOVDD] pins

Note3 Applied to the [CPVDD], [CPBUFVDD], [PVDD], [VCOVDD] and [OAVDD] pins

8. Electrical Characteristics

1. Digital DC Characteristics

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit	Remarks
High level input voltage	Vih		0.8×VDD1			V	Note 1)
Low level input voltage	Vil				0.2×VDD1	V	Note 1)
High level input current 1	Iih1	Vih = VDD1=5.25V	-1		1	μΑ	Note 1)
High level input current 2	Iih2	Vih = VDD2=5.25V	27	53	106	μΑ	Note 2)
Low level input current	Iil	Vil = 0V, VDD1=5.25V	-1		1	μΑ	Note 1)
High level output voltage	Voh	$Ioh = -500\mu A$	VDD1-0.4			V	Note 3)
Low level output voltage	Vol	$Iol = 500 \mu A$			0.4	V	Note 3)

Note1 Applied to the [CLK], [DATA], [LE], and [PDN] pins

Note2 Applied to the [TEST1] and [TEST2] pins

Note3 Applied to the [LD] pin

2. Serial Interface Timing

Write-In Timing> LE (Input) CLK (Input) DATA (Input) DO A3 A2 A1 A0

Fig.3 Serial Interface Timing

Serial Interface Timing

Parameter	Symbol	Min.	Тур.	Max.	Unit	Remarks
Clock L level hold time	Tcl	25			ns	
Clock H level hold time	Tch	25			ns	
Clock setup time	Tcsu	10			ns	
Data setup time	Tsu	10			ns	
Data hold time	Thd	10			ns	
LE setup time	Tlesu	10			ns	
LE pulse width	Tle	25			ns	

3. Analog Circuit Characteristics

VDD1=2.7~5.25V, VDD2=4.75~5.25V, VDD3=2.7~3.6V or 4.75~5.25V, -40°C < Ta < 85°C, CPBIAS=27kohm, MIXBIAS=33kohm, IF input frequency=200MHz, Internal VCO using unless otherwise specified.

RF Frequency Range 690 4000 MHz If Frequency Range 20 500 MHz Internal LO Frequency Range 262.5 4400 MHz LO Input Level 1 -5 0 +5 dBm {MODE}=2,differ or {MODE}=3} LO Input Level 2 -5 +1 dBm {MODE}=2, single dBm {LOLV}=3 LO Output Level @1GHz 6 dBm {LOLV}=2 0 dBm {LOLV}=2 0 dBm {LOLV}=1 0 dBm {LOLV}=0 0 dBm {LOLV}=0 0 dBm {LOLV}=0 0 with matching circ data and cir								
Internal LO Frequency Range 262.5 4400 MHz LO Input Level 1 -5 0 +5 dBm {MODE}=2,differ or {MODE}=3} LO Input Level 2 -5 +1 dBm {MODE}=2, single dBm {LOLV}=3 LO Output Level @1GHz 6 dBm {LOLV}=2 0 dBm {LOLV}=1 0 dBm {LOLV}=0 0 dBm dBm dBm 0 dBm dBm 0 dBm dBm 0 dBm dBm dBm								
LO Input Level 1 -5 0 +5 dBm {MODE}=2,differ or {MODE}=3 LO Input Level 2 -5 +1 dBm {MODE}=2, single dBm LO Output Level @1GHz 6 dBm {LOLV}=3 3 dBm {LOLV}=2 0 dBm {LOLV}=1 -6 dBm {LOLV}=0 Mixer Mixer Input impedance 50 Ω with matching circ Mixer Output impedance 200 Ω with matching circ Current Adjusting resistance 22 33 56 kΩ Connect to [MIXB RFOUT=2GHz Conversion Gain -4.5 -1.5 1.5 dB RF P1dB 7 10 dBm IIP2 70 dBm IIP3 20 24 dBm guaranteed by desi NF 13 17 dB guaranteed by desi Local Leakage LO-to-RF -50 dBc Use external Local								
LO Input Level 2 -5								
LO Output Level @1GHz	ential input							
3 dBm {LOLV}=2 0 dBm {LOLV}=1 -6 dBm {LOLV}=0	e input							
0 dBm {LOLV}=1 -6 dBm {LOLV}=0 -6 Mixer -6 Mixer -6 Mixer -6 Mixer -7 Mixer								
Mixer Input impedance 50 Ω with matching circ								
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NF 13 17 dB guaranteed by desi Local Leakage LO-to-RF -50 dBm Use internal VCO -50 dBc Use external Local								
Local Leakage LO-to-RF	gn							
-50 dBc Use external Local	gn							
Local Leakage LO-to-IF -80 dBm Use internal VCO								
-70 dBc Use external Local								
RFOUT=1GHz								
NF 11 dB								
RFOUT=4GHz								
NF 16 dB								

Item		Min.	Тур.	Max.	Unit	Remark			
REFIN characteristics									
Input Sensitivi	ty	0.4		2	Vpp				
Input Frequence	су	10		300	MHz				
		Phas	e Freque	ncy Det	ector				
PFD frequency	y	1.2		40	MHz				
			Charge	Pump					
CP Maximum	current		2400		μΑ				
CP Minimum	current		300		μΑ				
Icp TRI-STAT	E leak current		1		nA	Ta=25°C			
CP Output Rai	nge	0.5		VDD3	V				
		0.5		-0.5					
CP current adj	CP current adjusting resistance		27	33	kΩ	Connect to [CPBIAS] pin			
Normalized Phase Noise			-218		dBc/Hz				
			VC	0					
Operating Free	Operating Frequency Range			3000	MHz	VCO1			
		3000		3400	MHz	VCO2			
		3400		4400	MHz	VCO3			
VCO sensitivity			fv×0.02		MHz/V	fv: Oscillation Frequency			
Phase Noise	10kHz offset		-85		dBc/Hz				
@2.1GHz	100kHz offset		-111		dBc/Hz				
	1MHz offset		-132		dBc/Hz				
	10MHz offset		-152		dBc/Hz				

Item	Min.	Тур.	Max.	Unit	Remark			
Current Consumption								
IDD1		1	2	mA	[PDN]="L"			
IDD2		140	200	mA	[PDN]="H",{MIXEN}=1, {MODE}=0,{DIV}=0			
IDD3		150	210	mA	[PDN]="H",{MIXEN}=1, {MODE}=0,{DIV}≥2			
IDD4		190	270	mA	[PDN]="H",{MIXEN}=1, {MODE}=1,{DIV}≥2			

9. Block Functional Descriptions

· Operation Mode

AK1575 operation is controlled as follows by the [PDN] pin and registers.

Function	Pin	Pin Registers			Operating state					
Function	[PDN]	{MIXEN}	MODE[1]	MODE[2]	Mixer	Synthesizer	vco	Local Out		
StandBy1	"L"	X	X	X	OFF	OFF	OFF	OFF		
Prohibited	"H"	0	0	0	OFF	ON	ON	OFF		
Func1	"H"	0	0	1	OFF	ON	ON	Output		
Func2	"H"	0	1	0	OFF	ON	OFF	Input		
StandBy2	"H"	0	1	1	OFF	OFF	OFF	OFF		
Func3	"H"	1	0	0	ON	ON	ON	OFF		
Func4	"H"	1	0	1	ON	ON	ON	Output		
Func5	"H"	1	1	0	ON	ON	OFF	Input		
Func6	"H"	1	1	1	ON	OFF	OFF	Input		

StandBy1:Stand-by mode. Current consumption is minimized. It is available to write to the registers.

Func1: VCO and Synthesizer are active and Local signal outputs from [LOP] and [LON] pins.

Func2:Only Synthesizer is active. PLL operation is available with the external VCO.

StandBy2: Stand-by mode. Current consumption is minimized. It is available to write to the registers.

Func3: VCO, Synthesizer and Mixer are active.

Func4: VCO, Synthesizer and Mixer are active and Local signal outputs from [LOP] and [LON] pins.

Func5: Synthesizer and Mixer are active. PLL operation is available with the external VCO.

Func6: Only Mixer is active. A local signal needs to be input from [LOP] and [LON] pins.

10. Loop filter /Charge Pump

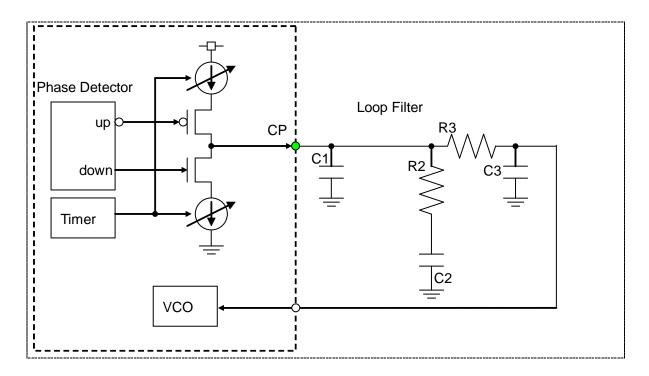


Fig.4 Loop Filter Schematic

11. Register Map

Name	Data	Address					
Freq1		0	0	0	1		
Freq2	D10 D0	0	0	1	0		
Freq3	D19 - D0	0	0	1	1		
Function		0	1	0	0		

Name	D19	D18	D17	D16	D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D 0	Address
Freq1	0	0	0	VCO [1]	VCO [0]	DIV [1]	DIV [0]	0	INT [11]	INT [10]	INT [9]	INT [8]	INT [7]	INT [6]	INT [5]	INT [4]	INT [3]	INT [2]	INT [1]	INT [0]	0x01
Freq2	0	CP1 [2]	CP1 [1]	CP1 [0]	0	CP2 [2]	CP2 [1]	CP2 [0]	FRAC [11]	FRAC [10]	FRAC [9]	FRAC [8]	FRAC [7]	FRAC [6]	FRAC [5]	FRAC [4]	FRAC [3]	FRAC [2]	FRAC [1]	FRAC [0]	0x02
Freq3	R [7]	R [6]	R [5]	R [4]	R [3]	R [2]	R [1]	R [0]	MOD [11]	MOD [10]	MOD [9]	MOD [8]	MOD [7]	MOD [6]	MOD [5]	MOD [4]	MOD [3]	MOD [2]	MOD [1]	MOD [0]	0x03
Function	CALTM [3]	CALTM [2]	CALTM [1]	CALTM [0]	0	LDCNT SEL	LD	MTLD	FAST EN	FAST [3]	FAST [2]	FAST [1]	FAST [0]	CP HIZ	DSM ON	MIX EN	MODE [1]	MODE [0]	LOLV [1]	LOLV [0]	0x04

Notes for writing into registers

1) The setting of <Address 0x02> and <Address 0x03> is reflected to each circuit when writing to <Address 0x01>.

2) <Address 0x04> behavior is reflected by itself.

When AK1575 powers on, the initial registers value is not defined. It is required to write the data in all addresses in order to commit it.

< Address0x01:Freq1 >

D [16:15]

VCO[1:0] : Select VCO

In accordance with the used frequency, select the VCO.

VCO[1:0]	VCO oscillating range		
Dec	Frequency		
0	2.1GHz~3.0GHz		
1	3.0GHz~3.4GHz		
2	3.4GHz~4.4GHZ		
3	prohibited		

D [14:13]

DIV[1:0]: LoDivider

In accordance with the used frequency, select the division number.

DIV[1:0]	LoDivider
Dec	Divide Number
0	No divide
1	2 divide
2	4 divide
3	8 divide

D [11:0]

INT[11:0] : NDivider

N divider divided number.

The allowed range is 35 to 4091.

< Address0x02:Freq2 >

D [18: 16]

CP1[2:0]: Set the charge pump current for normal status

D [14:12]

CP2[2:0]: Set the charge pump current for fast lock

CP1 is the charge pump current setting of the normal mode.

CP2 is the charge pump current setting of the fast lock mode

Charge pump current is determined by the following formula.

Charge pump current [A] = $Icp_min[A] \times (CP1 \text{ or } CP2 \text{ setting value}+1)$

 $Icp_min [A] = 8.1 / R [ohm]$

R: the resistance value which is connected to [CPBIAS] pin

Charge pump current (typ) unit : µA

CP1[2:0]		R	
CP2[2:0]	$33k\Omega$	$27\mathrm{k}\Omega$	22kΩ
0	245	300	368
1	491	600	736
2	736	900	1105
3	982	1200	1473
4	1227	1500	1841
5	1473	1800	2209
6	1718	2100	2577
7	1964	2400	2945

D [11:0]

$FRAC \hbox{$[11:0]$:} Fractional \ Numerator \ determination$

Set the Numerator of Fractional divider.

The allowed range is from 0 to (MOD[11:0] -1).

< Address0x03:Freq3 >

D[19:12]

R [7:0]: 8bit Reference Counter

Maximum PFD frequency is 40MHz

R[13:0]	Divide Ratio
0	Prohibited
1	1
2	2
3	3
4	4
•	•
•	•
•	•
253	253
254	254
255	255

D [11:0]

MOD[11:0]: Fractional Denominator determination

Set the denominator of Fractional divider.

The allowed range is from 2 to 4095.

< Address0x04: function >

D[19:16]

CALTM [3:0]: Set the calibration precision of VCO

The register {CALTM [3:0]} determines the calibration precision and time for VCO. When {CALTM [3:0]} is larger, the calibration precision increases, but the required time becomes long as trade-off. The value calculated by the following formula is recommended to get enough calibration precision. However, {CALTM [3:0]} should be set between from 1 to 11. 0 and over 11 is prohibited.

$$\{CALTM[3:0]\} \ge log_2(F_{PFD}/20000)$$

 F_{PFD} : PFD frequency

The calibration time can be estimated as following calculation;

Calibration time =
$$1/F_{PFD} \times \{(6 + 2^{CALTM[3:0]}) \times 8 + 3\}$$

D [14]

LDCNTSEL: Lock Detect Precision

Set the counter value for digital lock detect.

LDCNTSEL	Function	
0	15 times Count	unlocked to locked
U	3 times Count	locked to unlocked
1	31 times Count	unlocked to locked
1	7 times Count	locked to unlocked

D [13]

LD: Lock detect function

Set the lock detect function.

0: Digital lock detect

1: Analog lock detect

D [12]

MTLD: Local signal mute

0: Don't mute local signal in unlock state.

1: Mute local signal in unlock state.

 \Re Please use $\{MTLD\} = 0$ at the time of $\{LD\} = 1$.

D [11]

FASTEN: Fast Lock mode setting

Enable / disable fast lock mode.

0: Disable fast lock mode

1: Enable fast lock mode

Please refer to "14. Fast lock mode" for details.

D[10:7]

FAST [3:0]: Fast lock timer setting

Set the count number of fast lock timer.

Count Number = $511 + FAST[3:0] \times 512$

TIMER[3:0]	Count Number
0	511
1	1023
2	1535
3	2047
4	2559
5	3071
6	3583
7	4095
8	4607
9	5119
10	5631
11	6143
12	6655
13	7167
14	7679
15	8191

D [6]

CPHIZ: Charge Pump TRI-STATE

Set the charge pump output in Tri-State.

0: Normal

1: Tri-State

D [5]

DSMON: $\Delta\Sigma$ -modulator activation

In Integer-N setting, set the $\Delta\Sigma\text{-modulator}$ to active.

0: $\Delta\Sigma$ -modulator inactive

1: $\Delta\Sigma$ -modulator active

D [4]

MIXEN: Mixer Enable

0: Stand-by

1: Enable

D [3:2]

MODE [1:0]: Local operation mode

Set the operation of Synthesizer, VCO and LOP/LON pins.

MODE[1:0]	Local Operating MODE
0	Internal Synthesizer and VCO are active.
1	Internal Synthesizer and VCO are active and the local signal outputs from LOP/LON pins.
2	The mode operating external VCO with internal synthesizer.
3	The mode using an external local signal.

D [1:0]

LOLV [1:0]: Local output power

At the state of {MODE [1:0]} =1, set the power of the local signal output from LOP/LON pins.

LOLV[1:0]	LOP, LON output power [dBm]
0	-6
1	0
2	3
3	6

12. Lock Detect

Lock detect output can be selected by {LD} in D [13] of <Address0x04>. When {LD} is set to "1", the [LD] pin outputs a phase comparison result which is from phase detector directly. (This is called "analog lock detect".) When {LD} is set to "0", the output is the lock detect signal according to the on-chip logic. (This is called "digital lock detect".)

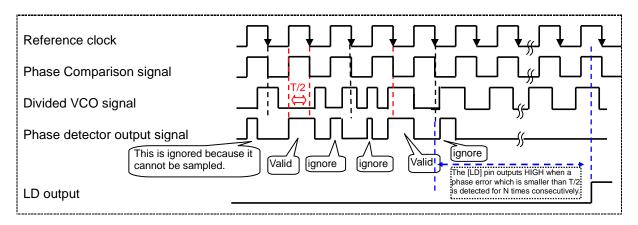
The digital lock detect can be done as following:

The [LD] pin is in unlocked state (which outputs "L") when a frequency setup is made.

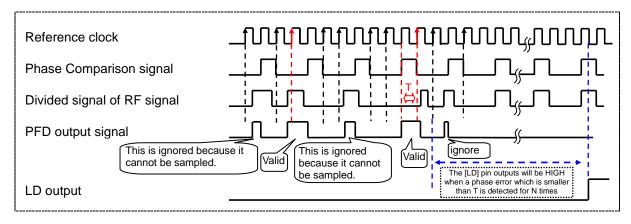
In the digital lock detect, the [LD] pin outputs "H" (which means the locked state) when a phase error smaller than a cycle of [REFIN] clock (T) is detected for N times consecutively. When a phase error larger than T is detected for N times consecutively while the [LD] pin outputs "H", then the [LD] pin outputs "L" (which means the unlocked state). The counter value N can be set by {LDCNTSEL} in D [14] of <Address0x04>. The N is different between "unlocked to locked" and "locked to unlocked".

{LDCNTSEL}	unlocked to locked	locked to unlocked
0	N=15	N=3
1	N=31	N=7

The lock detect signal is shown below

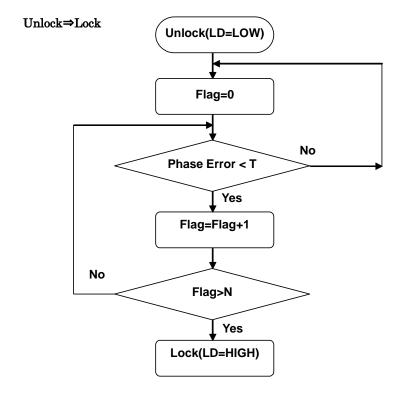


Case of "R = 1"

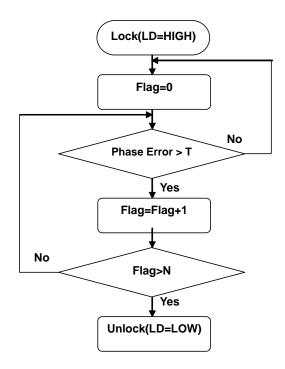


Case of "R > 1"

Fig6. .Digital Lock Detect Operations



Lock⇒unlock



13. Frequency Setup

The following formula is used to calculate the frequency setting for the AK1575.

Frequency setting = Ref Frequency \times (INT+FRAC/MOD)

Ref Frequency : PFD fequency

INT :Integer divide Number (Refer to <Address 0x01>:INT[11:0])

FRAC : Numenator setting number (Refer to <Address 0x02>:FRAC[11:0])

MOD : Denominator setting number (Refer to <Address 0x03>:MOD[11:0])

Set in the range of 35 to 4091 for INT[11:0].

Set in the range of 0 to (MOD-1) for FRAC[11:0]

Set in the range of 2 to 4095 for MOD[11:0]

Example

To complete Ref Frequency=19.2MHz, Frequency setting=2460.1MHz, set as follows

INT = 128 FRAC = 25 MOD = 192

Frequency setting = $19.2MHz \times (128 + (25 / 192)) = 2460.1MHz$

By writing <Address 0x01, 0x02, 0x03>, frequency is set. When <Address 0x01> is written, the setting of <Address 0x03> and <Addresses 0x02> is reflected in the internal circuit. At the time of the writing of <Address 0x01>, it is necessary for a synthesizer block to be powered on. The writing of <Address 0x01> as a trigger, frequency setting and VCO calibration are carried out, and fast lock counter starts operation. To set frequency definitely, <Address 0x01> should be written in the state that {MODE [1:0]} in <Address 0x04> is 0 or 1 or 2 and [PDN] pin is "H".

14. Fast Lock mode

The fast lock mode becomes effective when set $\{FASTEN\}$ of $\{Address\ 0x04\}$ to"1".

oFast Lock Mode

When writing in <Address0x01> with {FASTEN}=1, Fast Lock Up mode starts after calibration. The Fast Lock Up mode is valid only during the time period set by the timer according to the counter value in {FAST [3:0]} in <Address0x04>, and the charge pump current is set to the value specified by {CP2}. When the specified time period elapses, the Fast Lock Up mode operation is switched to the normal operation, and the charge pump current returns to {CP1} setting

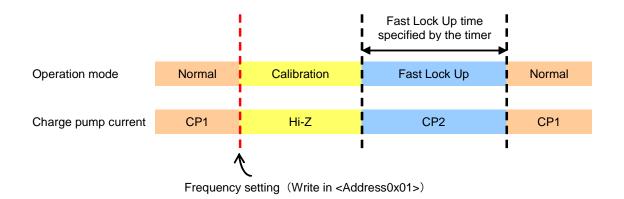


Fig.7. Fast Lock up Mode Timing Chart

Timer period

{FAST [3:0]} in <Address0x04> is used to set the time period for this mode. The following formula is used to calculate the time period

Counter Value = $511 + FAST[3:0] \times 512$

15. VCO

Calibration

AK1575 has three VCO core in uses several overlapping bands to allow low Phase Noise, low VCO sensitivity (K_{VCO}) and wide frequency range. The selection which VCO should be used can be done by the register {VCO[1:0]} in <Address 0x01>. Moreover, the correct band is chosen automatically at frequency setting, which is called calibration.

The calibration starts when <Address0x01> are written in the condition that $\{MODE[1]\}$ in <Address 0x04>="0" and [PDN] pin="H". During the calibration, V_{TUNE} of VCO is disconnected from the output of the loop filter and connected to an internal reference voltage. The charge pump output is disabled.

The internal bias must be stable so that the calibration is done correctly. Therefore, it is necessary to wait 500µsec at least until <Address0x01> writing after [PDN] rises up.

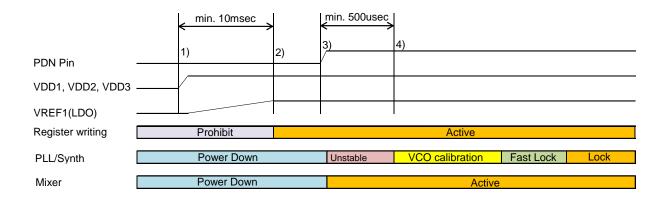
The register {CALTM [3:0]} determines the calibration time. When {CALTM [3:0]} is larger, the calibration precision increases, but the required time becomes long as a trade-off. The value calculated by the following formula is recommended to get enough calibration precision. However, {CALTM [3:0]} should be set at from 1 to 11. 0 and over 11 is prohibited.

$$\begin{aligned} & \{CALTM[3:0]\} \geq log_2(F_{PFD} \, / \, 20000) \\ & F_{PFD}: PFD \ frequency \end{aligned}$$

The calibration time can be estimated as following calculation;

Calibration time = $1/F_{PFD} \times \{(6 + 2^{\land} \{CALTM [3:0]\}) \times 8 + 3\}$

16. Power up Sequence



- 1) Set [PDN] pin to "L" and turn on power supplies (VDD1/VDD2/VDD3)
- 2) The stabilization time for [VREF1] (LDO) is 10msec. After LDO is stabilized, write the data to the registers of <Address 0x01, 0x02, 0x03, 0x04>
- 3) Set [PDN] pin to "H". In this state, the internal circuits are in an operating state, but PLL/Synth is unstable yet.
- 4) The stabilization time of internal BIAS circuits is 500usec. After BIAS circuit is stabilized, write the data to <Address 0x01>. VCO calibration starts and PLL status will be locked. Refer to 14.Fast Lock Mode and 15.VCO contents regarding fast Lock mode and VCO calibration.
- Note1) The initial register values are not defined. Therefore, it is required to write the data in all addresses of the register.
- Note2) The stabilization time for LDO is required more than 10ms.

17. Typical Evaluation Board Schematic

1.Evaluation Board schematic and the list of external parts

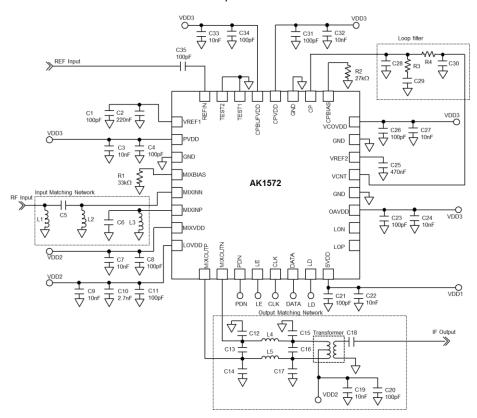


Fig.9. Typical Evaluation Board Schematic

Ref.	Value	Ref.	Value	Ref.	Value	Ref.	Value	Ref.	Value
C1	100pF	C10	2.7nF	C19	10nF	C28	Loop Filter	L2	Matching
C2	220nF	C11	100pF	C20	100pF	C29	Loop Filter	L3	Matching
C3	10nF	C12	Matching	C21	100pF	C30	Loop Filter	L4	Matching
C4	100pF	C13	Matching	C22	10nF	C31	100pF	L5	Matching
C5	Matching	C14	Matching	C23	100pF	C32	10nF	R1	33kΩ
C6	Matching	C15	Matching	C24	10nF	C33	10nF	R2	27kΩ
C7	10nF	C16	Matching	C25	470nF	C34	100pF	R3	Loop Filter
C8	100pF	C17	Matching	C26	100pF	C35	100pF	R4	Loop Filter
C9	10nF	C18	Matching	C27	10nF	L1	Matching		

Note1) Exposed Pad at the center of the backside is should be connected to ground.

Note2) [TEST1] and [TEST2] pins should be connected to ground.

2. External circuit to input the external Local signal to [LOP] and [LON] pins.

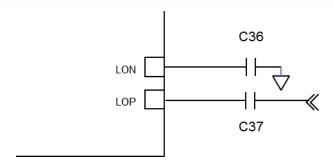


Fig 7 Circuit for local input

Ref	Value
C36	100pF
C37	100nF

3. External circuit to output the internal local signal from [LOP] and [LON] pins

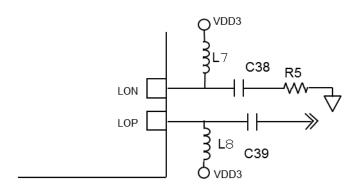


Fig 8 Circuit for local output

Example of the external components for this mode

Ref	Value
C38	100pF
C39	100pF
L7	180nH
L8	180nH
R5	50Ω

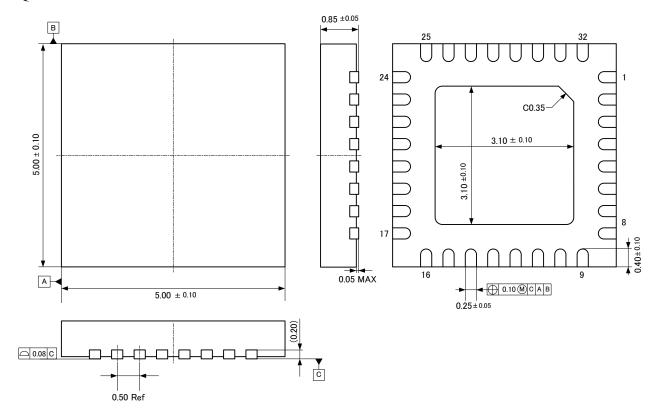
18. Interface Circuit

Pin No.	Name	I/O	R0 (Ω) (typ.)	Cur (µA)	Function
11	PDN	DI	300		
12	LE	DI	300		Digital input pin
13	CLK	DI	300		†
14	DATA	DI	300		_
					RO PO
					本
					rim
30	TEST1	DI	300		Digital input pin Pull-Down
31	TEST2	DI	300		<u> </u>
					RO .
					<u></u>
15	LD	DO			Digital Output pin
					<u></u>
					本
					, , , , , , , , , , , , , , , , , , ,
21	VCNT	I	100		Analog input pin
32	REFIN	Ι	300		<u></u>
					RO RO
					<u>,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,</u>
					,,,,,

Pin No.	Name	I/O	R0 (Ω) (typ.)	Cur (µA)	Function
1	VREF1	AO	300		Analog input/output pin
4	MIXBIAS	AO	300		
22	VREF2	AI	300		R0 W
25	CPBIAS	AI	300		
					nm .
23	CP	Ο			Analog output pin
9	MIXOUTN	О			RF open collector output pin
10	MIXOUTP	О]
17	LOP	IO			RF open collector input/output pin
18	LON	Ю			
5	MIXINN	IO			RF input pin
6	MIXINP	Ю			

19. Outer Dimensions

QFN32-5X5-0.50



Note) The exposed pad at the center of the backside should be connected to ground.

20. Marking

(a) Style : QFN
(b) Number of pins : 32
(c) 1 pin marking: : O
(d) Product number : 1575

(e) Date code : YWWL (4 digits)

Y: Lower 1 digit of calendar year (Year $2013 \rightarrow 3$, $2014 \rightarrow 4$...)

WW: Week

L: Lot identification, given to each product lot which is made in a week \rightarrow LOT ID is given in alphabetical order (A, B, C...).

1575_(d)
YWWL_(e)
(c)

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